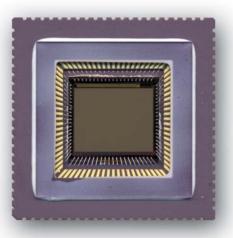


# **IBIS4-1300**

## **1.3 M Pixel Rolling Shutter CMOS Image Sensor**

**Datasheet** 





#### Overview

The IBIS4-1300 is a digital CMOS active pixel image sensor with SXGA format.

Due to a patented pixel configuration a 60% fill factor and 50% quantum efficiency are obtained. This is combined with an on-chip double sampling technique to cancel fixed pattern noise.

#### Main features

- SXGA resolution: 1280 x 1024 pixels
- High sensitivity 20 µV/electron
- High fill factor 60 %
- Quantum efficiency > 50% between 500 and 700 nm.
- 20 noise electrons = 50 noise photons
- Dynamic range: 66 dB (2000:1) in *single slope* operation
- Extended dynamic range mode (80...100 dB) in *double slope* integration
- On-chip 10 bit, 10 mega Samples/s ADC
- Programmable gain & offset output amplifier
- 4:1 sub sampling viewfinder mode (320x256 pixels)
- Electronic shutter
- $7 \times 7 \mu m^2$  pixels
- Low fixed pattern noise (1 % Vsat p/p)
- Low dark current: 344 pA/cm<sup>2</sup> (1055 electrons/s, 1 minute auto saturation)
- RGB or monochrome
- Digital (ADC) gamma correction

Part Number	Color or B/W
Ibis4-1300-M1	B&W
CYII4SM1300AA-HBC - Preliminary	ban
Ibis4-1300-C1	RGB diagonal stripes
CYII4SD1300AA-QAC - Preliminary	
Ibis4-1300-C2	RGB Bayer pattern
CYII4SC1300AA-QAC - Preliminary	5 1



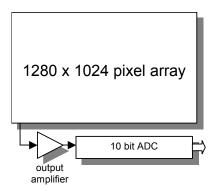
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## 1 Architecture of the image sensor

Block diagram



The IBIS4-1300 is an SXGA CMOS image sensor. The chip is composed of 3 modules: an image sensor core, a programmable gain output amplifier, and an on-chip 10 bit ADC.

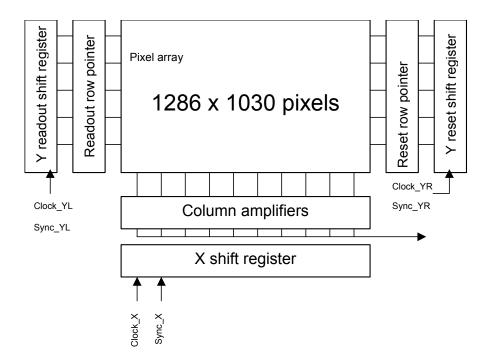


Figure 1: architecture of the image sensor core



### **1.1 Image sensor core – focal plane array**

Figure 1 shows the architecture of the image sensor core.

The core of the sensor is the pixel array with 1280 x 1024 (SXGA) active pixels.

The name 'active pixels' refers to the amplifying element in each pixel. This type of pixels offer a high light sensitivity combined with low temporal noise. The actual array size is 1286 x 1030 including the 6 dummy pixels in X and Y. Although the dummy pixels fall outside the SXGA format, their information can be used e.g. for color filter array interpolation.

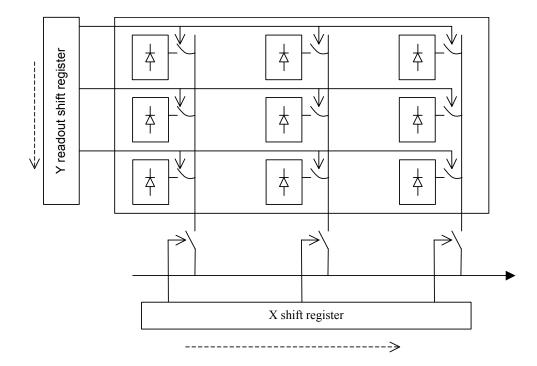


Figure 2: Pixel selection - principle

Next to the pixel array there are two Y shift registers, and one X shift register with the column amplifiers. The shift registers act as pointers to a certain row or column. The Y readout shift register accesses the row (line) of pixels that is currently readout. The X shift register selects a particular pixel of this row. The second Y shift register is used to point at the row of pixels that is reset. The delay between both Y row pointers determines the integration time -thus realizing the electronic shutter.

A clock and a synchronization pulse control the shift registers. On every clock pulse, the pointer shifts one row/column further. A sync pulse is used to reset and initialize the shift registers to their first position.

The smart column amplifiers compensate the offset variations between individual pixels. To do so, they need a specific pulse pattern on specific control signals before the start of the row readout.

Table 1 summarizes the optical and electrical characteristics of the image sensor. Some specifications are influenced by the output amplifier gain setting (e.g. temporal noise, conversion factor,...). Therefore, all specifications are referred to an output amplifier gain equal to 1.



#### Table 1: optical & electrical characteristics

#### **Pixel characteristics**

Pixel structure	3-transistor active pixel
Photodiode	High fill factor photodiode
Pixel size	$7 \text{ x} 7 \text{ um}^2$
Resolution	1286 x 1030 pixels
	SXGA plus 6 dummy rows & columns
Pixel rate with on-chip ADC	Nominal 10 MHz (note 1) (note 2)
Frame rate with on-chip ADC	About 7 full frames/s at nominal speed
Frame rate with analog output	Up to 23 full frames per second (see table1.1)

Table 1.1 In this table you find achievable values using the analog output

X pixels	Y pixels	X Freq	X Clock	X Blanking	line time	frame time	frame rate	pixel rate	pixel rate freq
#	#	Hz	sec	sec	sec	sec	per sec	sec	Hz
1286	1030	1,00E+07	1,00E-07	6,25E-06	0,000134850	0,138895500	7,20	1,049E-07	9536522
1286	1030	2,00E+07	5,00E-08	6,25E-06	0,000070550	0,072666500	13,76	5,486E-08	18228207
1286	1030	3,00E+07	3,33E-08	6,25E-06	0,000049117	0,050590167	19,77	3,819E-08	26182559
1286	1030	3,75E+07	2,67E-08	6,25E-06	0,000040543	0,041759633	23,95	3,153E-08	31719148
1286	512	3,75E+07	2,67E-08	6,25E-06	0,000040543	0,020758187	48,17	3,153E-08	31719148

Note 1. The pixel rate can be boosted to 37.5 MHz. This requires a few measures.

-increase the analog bandwidth by halving the resistor on pin Nbias\_oamp

-increase the ADC speed by the resistors related to the ADC speed (*nbiasana1*, *nbiasana2*, *pbiasencload*)

-experimentally fine tune the relative occurrence of the ADC clock relative to the X-pixel clock.

Note 2. The pure digital scan speed in X and Y direction is roughly 50 MHz. This is the maximum speed for skipping rows and columns.

#### Light sensitivity & detection

<u> </u>	
Spectral sensitivity range	400 – 1000 nm
Spectral response * fill factor	0.165 A/W @ 700 nm
Quantum efficiency * fill factor	> 30 % between 500 & 700 nm
Fill factor	60 %
Charge-to-voltage conversion gain	$18 \mu\text{V/electron}$
Output signal amplitude	1.2 V
Full well charge [electrons]	IBIS4-1300: about 70000 saturation, 50000 linear range
Noise equivalent flux at focal plane	1.1e-4 lx*s (at focal plane)
(700 nm)	6.3 e-7 s.W/m2
Sensitivity	7 V/lx.s
	1260 V.m2/W.s
MTF @ Nyquist frequency	0.4-0.5 @ 450 nm
	0.25-0.35 @ 650 nm
Optical cross talk	10% to 1 <sup>st</sup> neighbor
	2 % to 2 <sup>nd</sup> neighbor

#### **Image quality**

Temporal noise (dark, short integration time)	20 noise electrons $=50$ peak noise photons (*)
	500 μV RMS
Dynamic range	2000:1
(analog output, before ADC conversion)	66 dB
Dark current	344 pA/cm <sup>2</sup> @ 21°C
	19 mV/s



	1055 electrons/s
Dark current non-uniformity	Typically 15% RMS of dark current level.
Fixed pattern noise	9.6 mV peak-to-peak
(dark, short integration time)	1-2 mV RMS
Photo-response non-uniformity (PRNU)	10 % peak-to-peak @ 1/2 of saturation signal
Yield criteria	No missing columns nor rows
	Less than 100 missing pixels, clusters=<4 pixels
Anti-blooming	Overexposure suppression $> 10^5$
Smear	Absent

(\*) peak noise photons are defined as (noise electrons) / (FF\*peak QE)

#### Features & general specifications

Electronic shutter	Rolling curtain type		
	Increment = line time = $135$ us		
Viewfinder mode	4 x sub-sampling (320 x 256 pixels)		
Digital output	10 bit		
Color filter array	Primary colors (Red, Green, Blue)		
-	RGB diagonal stripe pattern or Bayer pattern		
Die size	$10.30 \times 9.30 \text{ mm}^2$		
Package	84 pins LCC chip carrier		
-	0.460 inch cavity		
Supply voltage	5 V stabilized (e.g. from a 7805 regulator)		
Power supply feed trough (dVout/dVdd)	< 0.3 for low-frequencies ( < 1 MHz)		
	< 0.05 for high frequencies ( $> 1$ MHz)		
Power dissipation (continuous operation, 10	Min. 50 mA Typ. 70 mA Max. 90 mA		
MHz, ADC outputs loaded)			

#### 1.1.1 Light sensitivity

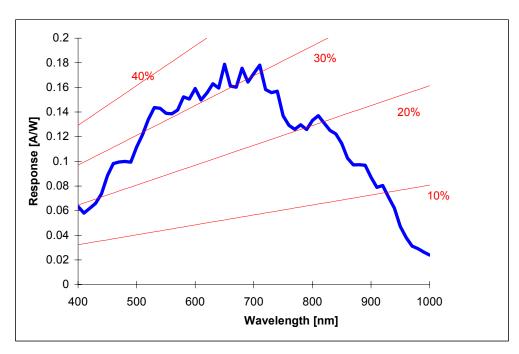


Figure 3: spectral response \* fill factor of the IBIS4-1300 pixels



Figure 3 shows the spectral response characteristic. The curve is measured directly on the pixels. It includes effects of non-sensitive areas in the pixel, e.g. interconnection lines. The sensor is light sensitive between 400 and 1000 nm. The peak QE \* FF is more than 30% between 500 and 700 nm. In view of a fill factor of 60%, the QE is thus larger than 50% between 500 and 700 nm.

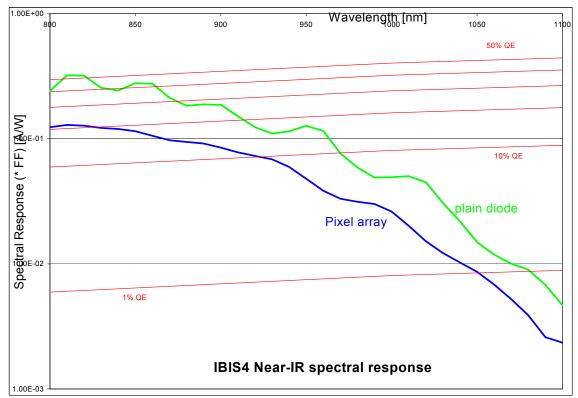


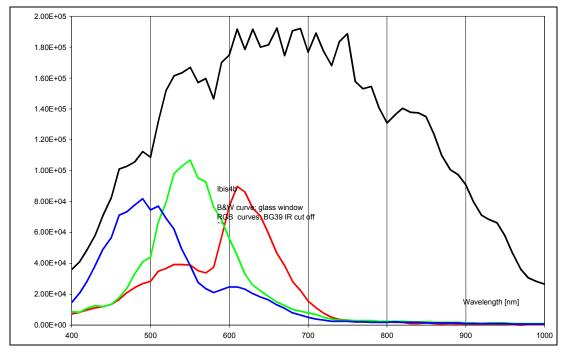
Figure 4: Near infrared spectral response

calculation	of sensitivity	in	[V/lx.s]
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Pixel area A	49 E-12 m2
Fill factor FF	60%
Spectral response SR	0.22 A/W (average)
FF*SR	0.13 A/W (average over wavelength)
Pixel capacitance Ceff	5E-15 F
Sensitivity = FF*SR*Ceff/A	1.27E+3 [V.W/s.m2]
Conversion to lux: $1W/m2 =$	About 180 lux, visible light only
	About 70 lux, including Near Infrared
Sensitivity in lux units:	7.08 [V/lx.s] visible light only
	18 [V/lx.s] if near IR included.

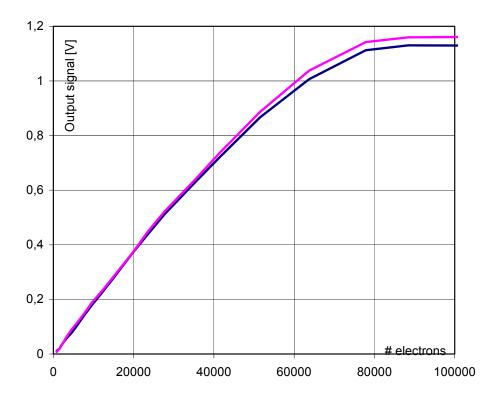


#### 1.1.2 Color sensitivity









#### 1.1.3 Charge conversion - Conversion of electrons in an output signal

*Figure 5: IBIS4-1300 response curve – two pixels – lowest gain setting (0000)* 

Figure 5 shows the pixel response curve in linear response mode. This curve is the relation between the electrons detected in the pixel and the output signal. This curve was measured with light of 600 nm, with an integration time of 138.75 ms (10 MHz pixel rate), at minimal gain setting 0000. The resulting voltage/electron curve is independent of these parameters. The conversion gain is 18 uV/electron for this gain setting.

Note that the upper part of the curve (near saturation) is actually a logarithmic response, similar to the FUGA1000 sensor. The level of saturation can be adjusted by the voltage on GND-AB. However note also that this logarithmic part of the response is not FPN corrected by the on-chip offset correction circuitry.

The signal swing (and thus the dynamic range) is extended by increasing the VDD\_RESET (pins 59/79) to 5.5 V. This is mode of operation is not further documented.



Table 2 shows the pins of the IC that are related to the image sensor core, describing their functionality.

Digital controls		
SYNC_YR\	5	Reset right Y shift register (low active, $0 = \text{sync}$ )
CLK_YR	6	Clock right Y shift register (shifts on falling edge)
EOS_YR\	7	(output) low 1 <sup>st</sup> CLK_YR pulse after last row (low active)
SYNC X\	28	Reset X shift register (low active, $0 = sync$ )
CLK X	29	Clock X shift register (shifts on falling edge)
EOS X	8	(output) Low 1 <sup>st</sup> CLK_X pulse after last active column (low active)
SYNC YL	36	Reset left Y shift register (low active, $0 = \text{sync}$ )
CLK YL	37	Clock left Y shift register (shifts on falling edge)
EOS YL\	38	Low 1 <sup>st</sup> CLK_YL pulse after last row
SHY	30	Parallel Y track & hold (1 = hold, 0 = track)
5111	50	apply pulse pattern – see sensor timing diagram
SIN	35	Column amplifier calibration pulse
5114	55	1 = calibrate - see sensor timing diagram
SELECT	40	Selects row indicated by left/right shift register
SELECT	40	high active (1= select row)
		Apply 5 V DC for normal operation
RESET	41	Resets row indicated by left/right shift register
NEOE I	41	
		high active (1 = reset)
I /D\	80	Apply pulse pattern – see timing diagram
L/R\	80	Use left or right register for SELECT and RESET 1 = 100 (0 = right)
	0.4	1 = left / 0 = right - see sensor timing
SUBSMPL	84	Activate viewfinder mode (1:4 sub sampling = $320 \times 256$ pixels)
		high active, 1 = sub sampling
Reference voltage		
DCCON	31	Control voltage for the DCREF voltage generation
		Connect to ground by default
DCREF	32	Reference voltage (output), to be decoupled to GND
		Should be about 1.2V, can be adjusted by DCCON
NBIASARRAY	1	1 MegaOhm to VDD and decouple to ground by 100 nF capacitor
PBIAS2	2	1 MegaOhm to ground and decouple to VDD by 100 nF capacitor
PBIAS	3	1 MegaOhm to ground and decouple to VDD by 100 nF capacitor
XMUX NBIAS	4	100K to VDD and decouple to ground by 100 nF capacitor
GND_AB	54	Anti-blooming drain control voltage
5.10_10	57	<ul> <li>Default: connect to ground. The anti blooming is operational but not</li> </ul>
		<ul> <li>Default, connect to ground. The anti-bioonning is operational but not maximal.</li> </ul>
		Apply about 1 V DC for improved anti-blooming
<b>D</b> 0 -		
Power & ground		
VDD_RESETL	59	Power supply for left reset line drivers
		apply 5 V DC (default) or about 44.5 V for dual slope mode
VDD_RESETR	79	Power supply for right (default) reset line drivers
		5 V DC
VDD_ARRAY	55	Power supply for the pixel array
—		5 V DC
VDD	11	Power supply of image sensor core & output amplifier
	34	5 V DC
	53	
	//	
GND	77	Ground of image sensor core & output amplifier
GND	10	Ground of image sensor core & output amplifier
GND	10 33	Ground of image sensor core & output amplifier
GND	10	Ground of image sensor core & output amplifier



## 1.2 Output amplifier

The output amplifier stage is user-programmable for gain and offset level. Gain and offset are controlled by 4-bit wide words. Gain settings are on an exponential scale. Offset is controlled by a 4-bit wide DAC, which selects the offset voltage between 2 reference voltages (Vhigh\_dac & Vlow\_dac) on a linear scale.

The offset setting is independent of the gain setting.

The gain setting is independent of amplifier bandwidth.

The amplifier is designed to match the specifications like the output of the imager array. This signal has a data rate of 10 MHz and is located between 1.2 and 2.4 V. Table 3 summarizes the specifications of the amplifier.

	Min	Тур	Max
Gain	1.2 (gain setting 0)	2.7 (setting 4)	16 (setting 15)
Output signal range	1 V		4.5 V
Bandwidth (40 pF load)	12 MHz (gain setting 15)	22 MHz (gain setting 08)	33 MHz (gain setting 0)
Output slew rate (40 pF load)	40 V/µs	50 V/µs	80 V/µs

Table 3: summary of output amplifier specifications

The range of the output stage input is between 1 and 4 V. A lowest gain the sensor outputs a signal in between 1.2 and 2.2 V, which fits into the input range of the amplifier. The range of the output signal is between 1 and 4.5 V, dependent on the gain and offset settings of the amplifier. This range should fit to the input range of the ADC, external or internal. The on-chip ADC range is between 2 and 4 V. A minimal gain setting of "3" seems necessary for the internal ADC, and the offset voltage should be set to the low-reference voltage of the ADC.

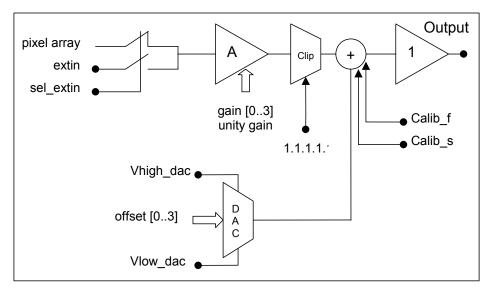


Figure 6: output amplifier architecture



Figure 6 shows the architecture of the output amplifier. First of all, there is a multiplexer which selects either the imager core signal or an external pin EXTIN as the input of the amplifier. EXTIN can be used for evaluation, or to feed alternative data to the output.

SEL\_EXTIN controls this switch.

Then, the signal is fed to the first amplifier stage. This stage has an adjustable gain, controlled by a 4-bit word ('gc\_bit0...3').

Then, the upper level of the signal must be clipped in some situations (clipping sometimes is necessary when the imager signal is highly saturated, which affects the calibration level. This is visible as black banding at the right side of bright objects in the scene). In order to do this, a voltage should be applied to the 'Clip' pin. The signal is clipped if it is higher than Vclip - Vth,pmos, where Vth,pmos is the PMOS threshold voltage and is typically –1 V. If clipping is not necessary, 5 V should be applied to 'Clip'.

After this, the offset level is added. This offset level is set by a DAC, controlled by a 4-bit word (DAC\_bit0...3). The offset level can be calibrated in two modes : fast offset adjustment or slow offset adjustment. This is controlled by 'calib\_s' and 'calib\_f'. The slow adjustment yields a somewhat cleaner image.

After this, the signal is buffered by a unity feedback amplifier and it leaves the chip. This 2<sup>nd</sup> amplifier stage determines the maximal readout speed, i.e. the bandwidth and the slew rate of the output signal. The whole amplifier chain is designed for a data rate of 10 Mpix/s (@ 40 pF). (It is up to the experimenter to increase this speed by reducing the various setting resistors)

Table 4 shows the IBIS4-1300 pins used by the output amplifier with a short functional description. Power and ground lines are shared between the output amplifier and the image sensor.

#### 1.2.1 Output amplifier offset level adjustment

The purpose of this adjustment is to bring the pixel voltage range as good as possible within the ADC range. The offset level of the output signal is controlled by a 4-bit resistive DAC. This DAC selects the offset level on a linear scale between 2 reference voltages. These reference voltages are applied to Vlow\_dac and Vhigh\_dac.

This offset level is adjusted during the calibration phase. During this phase, the amplifier input should be constant and refers to the 'zero' signal situation. The IBIS4-1300 outputs a dark reference signal after a row has been read out completely. This signal can be used as the 'zero signal' reference. Alternatively one can apply an external reference on pin EXTIN, which is applied to the output amplifier when SEL\_EXTIN is 1.

Offset adjustment can be done during row or frame blanking time.

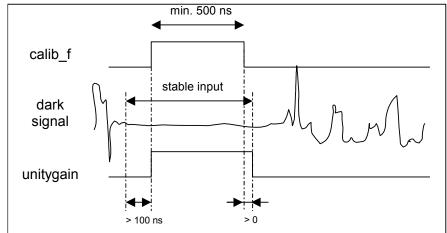


Figure 7 : offset adjustment : fast offset adjustment mode



There are 2 modes of offset calibration for the output amplifier: *slow* and *fast* adjustment. Figure 7 shows the timing and signal waveforms for fast offset adjustment mode. Closing both 'calib\_f' and 'unitygain' operates it. After 'calib\_f' is opened again, the offset level is adjusted to the desired value in a single cycle. The signal applied to the output amplifier should be stable just before and during the adjustment phase. The same is true for the DAC output.

The signal applied to the output amplifier can be either:

- The signal generated by the electrical dark reference in the imager core itself, i.e. the pixels named "dark" in Figure 20.
- Apply the reference from outside on the pin EXTIN, controlled by SEL\_EXTIN.

If this fast offset adjustment is used, it should be done once each frame, before the readout of the frame starts, e.g. during the blanking time of the first line.

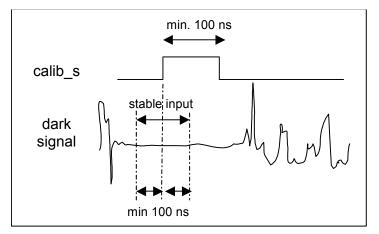


Figure 8: slow offset adjustment mode

Figure 8 shows the timing and signal waveforms for slow offset adjustment mode. It is operated by pulsing 'calib\_s'. The amplifier input signal must be stable and refer to 'dark' signal at the moment when calib\_s goes low. The offset is slowly adjusted with a time constant of about 100 of these pulses. One pulse is then generated during each row blanking time.

The baseline is to use the fast calibration once per image. The slow calibration is intended as alternative if, for very slow readout, the offset drifts during the image.



 Table 4: pins involved in output amplifier circuitry

Name	No.	Function
Analog sign	als	
Extin	12	External input of the output amplifier
_		Active if Sel_extin = 1
Output	13	Analog output signal
		To be connected to the input of the ADC (in_adc, pin 73)
Digital Con	trols	
Sel_extin	9	1 = external input pin (extin) is applied at the input of the amplifier
		0 = output amplifier is connected to the image sensor array
gc_bit0	17	LSB
gc_bit1	18	Control hits for output overlifter onin acting
gc_bit2	19	Control bits for output amplifier gain setting Gain adjustment between 1.2 (0000) & 16X (1111)
gc_bit3	20	MSB
unitygain	21	1 = output amplifier in unity feedback mode
		$0 =$ output amplifier gain controlled by gc_bit03
calib_s	16	Slow (or incremental) output offset level adjustment (calibration of output
		amplifier). Offset adjustment converges after about 100 pulses on calib_s
		Amplifier input should refer to a 'zero signal' at the moment of the 1->0
		transition on calib_s 0 = connect to capacitor (of stage 2) and in- (of stage 1)
		1 = connect to Capacitor (of stage 2) and in- (of stage 1) 1 = connect to DAC output (of stage 2) and out (of stage 1)
calib f	22	Fast (=in 1 cycle) output offset level adjustment (calibration of output
cano_i	22	amplifier)
		Offset level is adjusted when both calib f and unitygain are high
		Amplifier input should refer to 'zero signal' when calib f is high
		1 = connect DAC output to offset of capacitor
		0 = DAC output disconnected
dac_b0	26	LSB
dac_b1	25	Control hits for output offect lovel a divetment
dac_b2	24	Control bits for output offset level adjustment Between Vlow dac (0000) & Vhigh dac (1111)
dac b3	23	MSB

#### **Reference voltages**

Vlow_dac	14	Low and high references for offset control DAC of the analog output.
Vhigh_dac	15	The range of this resistive division DAC should be about 1V to 2.5V. If the range is not OK, one will notice that it is not possible to adjust the output voltage to the appropriate level of the ADC. As the internal division resistor is about 1.3 Kohm, we suggest to tie Vlow_dac with 1K to GND and Vhigh_dac with 2K7 to VDD.
Nbias_oamp	27	Output amplifier speed/power. Connect with 100 K to VDD and decouple with 100 nF to GND. <i>This setting yields 10 MHz nominal pixel rate. Lowering the resistance does increasing this rate.</i>
Clip	83	Voltage that can be used to clip the output signal Clips output if output signal > 'Vclip - Vth, PMOS' with Vth,PMOS=-1V Default: 5 V (no clipping)





#### 1.2.2 Output amplifier gain control

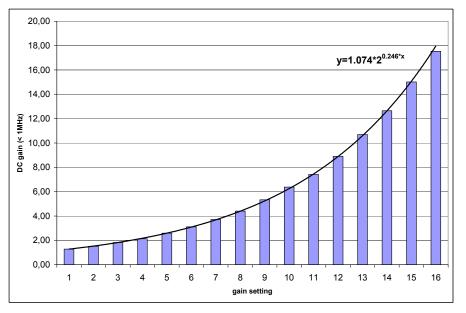


Figure 9: output amplifier DC gain

gain setting	DC gain (<1MHz)	gain setting	DC gain (<1MHz
0000	1.28	1000	5.33
0001	1.51	1001	6.37
0010	1.82	1010	7.41
0011	2.13	1011	8.91
0100	2.60	1100	10.70
0101	3.11	1101	12.65
0110	3.71	1110	15.01
0111	4.40	1111	17.53

Table 5 : DC gain of output amplifier for different gain settings

The output amplifier gain is controlled by a 4-bit word. In principle, the output amplifier can be configured in unity feedback mode by a permanent high signal on UNITYGAIN, but the purpose of this mode is purely diagnostic. The "normal" gain settings vary on an exponential scale. Figure 9 and Table 5 report all gain settings.

In first approximation, the gain setting is independent of bandwidth, as the amplifier is a 2-stage design. The first stage sets the gain, and the second stage is a unity gain buffer, that determines bandwidth and slew rate. There is however some influence of gain setting on bandwidth. Figure 10 shows the output amplifier bandwidth for all gain settings.



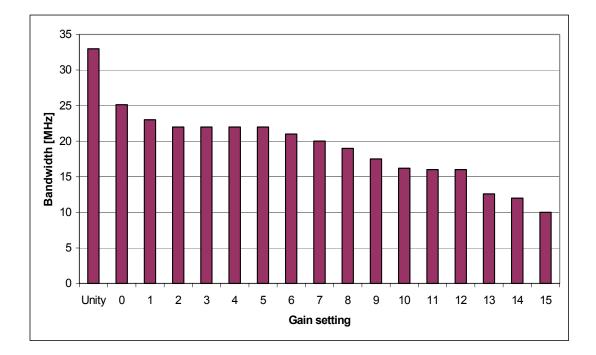


Figure 10: output amplifier bandwidth for different gain settings

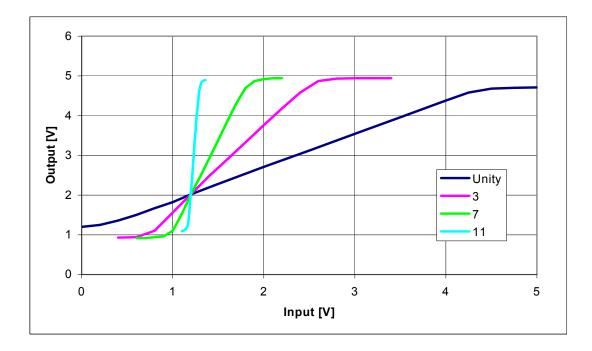


Figure 11: typical transfer characteristic of the output amplifier (no clipping, Voffset = 2 V, input signal during offset adjustment is 1.2 V)



Figure 11 shows the output characteristic curve in a typical case for the imager. The offset voltage is adjusted to 2 V, which corresponds to the low-level voltage of the ADC. Clipping is off, and the input signal is changed between 0 and 5 V. During offset adjustment (when calib\_s is switched from  $1 \rightarrow 0$  or when calib\_f is on), the input signal is at 1.2 V. This level corresponds to the imager dark reference output. The input signal is transferred to the output by adding a 2V offset and multiplication with the appropriate gain. The input signal of dark pixels (at 1.2 V) corresponds with 2 V at the output. Higher input signals are amplified. The curves for 3 typical gain settings are shown (unity gain, setting 3, 7 & 11).

Again, as can be seen on the above figure, the applied input signal during the output amplifier calibration (by 'CALIB\_S' or 'CALIB\_F') is the reference level to which the signal is amplified. During this calibration, a stable input is required.

#### 1.2.3 Setting of the VLOW\_DAC & VHIGH\_DAC reference voltages

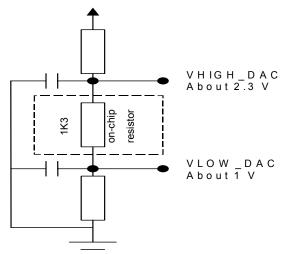


Figure 12: suggested circuit for high and low references of DAC

VLOW\_DAC & VHIGH\_DAC are the reference voltages for the DAC. They represent the 0000 resp. 1111 code. The internal series resistance is about 1.3 kOhms. They can be connected as in Figure 12, and decoupled to ground.

### 1.3 Analog to digital converter

The IBIS4-1300 has a 10 bit flash analog digital converter running nominally at 10 Msamples/s. The ADC is electrically separated from the image sensor. The input of the ADC ("IN\_ADC") should be tied externally to the OUTPUT of the output amplifier.

Input range	2-4 V
Quantization	10 Bits
Nominal data rate	10 Msamples/s (*)
DNL (linear conversion mode)	
INL (linear conversion mode)	
Input capacitance	< 20 pF
Power dissipation @ 10 MHz	107 mA
	535 mW
Delay of digital circuitry (Td, 40 pF load)	< 50 ns after falling edge of clock
Input setup time (Ts) for a stable LSB	< 100 ns before falling edge of clock
Conversion law	Linear / Gamma-corrected

Table 6: ADC specifications



(\*) Project partners have demonstrated 20 MHz data rate by careful timing and by decreasing some or all of the resistors on NBIAS\* and PBIAS\*.

#### 1.3.1 ADC timing

The ADC converts on the falling edge of the CLK\_ADC clock. The input signal should be stable during a time Ts before the falling clock edge. The digital output is available Td after the falling clock edge (Figure 13, Ts = 100 ns, Td = 50 ns). These values are the delays to obtain a stable LSB after a half-scale swing of the input signal. For the MSB to become stable, Ts=20 ns is sufficient. For a full scale input swing (which normally doesn't appear with image sensors), Ts is 140 ns for the LSB and 20 ns for the MSB.

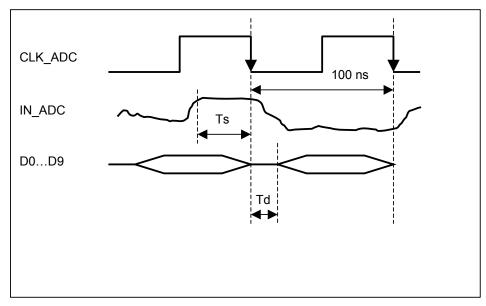


Figure 13: ADC timing

TRI\_ADC can be used to put the output bits in a tristate mode (e.g. for bi-directional busses). If this is used, the output signal becomes valid 50 ns after the falling edge on TRI\_ADC.

BITINVERT can be used to invert the output word, if necessary (one's complement).

When NONLINEAR is high, the ADC conversion is non-linear. The contrast will be higher in dark image regions, and lower in bright areas, similar to gamma correction.



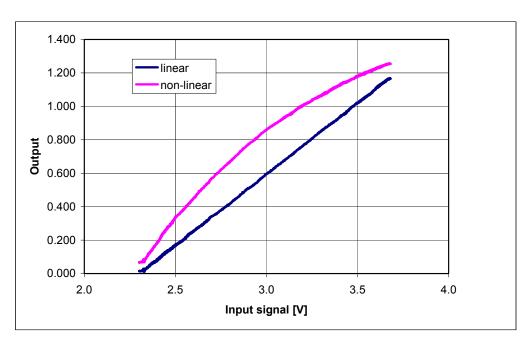
Table 7: pins of the ADC

Name	No.	Description
ivanc	110.	Description
Analog signals		
IN ADC	73	Input, connect to sensor's output (pin 13)
		Input range is between 2 & 4 V (VLOW ADC &
		VHIGH ADC)
<b>Digital Controls</b>		
CLK_ADC	62	ADC Clock
		ADC converts on falling edge
TRI_ADC	63	Tristate control of ADC digital outputs
		1 = tristate; 0 = output
NONLINEAR	67	1 = non-linear analog-digital conversion
		0 = linear analog-digital conversion
BITINVERT	39	1 = invert output bits
		0 = no inversion of output bits
Digital output		
DO D9	5142	Output bits
		D0 = LSB, D9 = MSB
Reference voltages	71	I are reference and high reference as the set of ADC should
VLOW_ADC VHIGH ADC	71 61	Low reference and high reference voltages of ADC should be 2V to 4V.
VHIGH_ADC	01	The resistance between VLOW ADC and VHIGH ADC
		is about 1.5 K, thus this range can be approximated by
		tying LOW with 2K to GND
		And HIGH with 1K to VDD.
PBIASDIG1	64	Connect with 100K to GND and decouple to VDD
PBIASENCLOAD	65	Connect with 100K to GND and decouple to VDD
PBIASDIG2	66	Connect with 100K to GND and decouple to VDD
NBIASANA2	69	Connect with 100K to VDD and decouple to VDD
NBIASANA	70	Connect with 100K to VDD and decouple to GND
		<i>These resistors determine the analog resp. digital speed</i>
		/power of the ADC. Both can be increased/decreased by
		lowering or increasing the resistance values.
Power & Ground		
VDD_DIG	56, 76	Power supply of digital circuits of ADC, + 5 V
VDD_AN	58, 74	Power supply of analog circuits of ADC, + 5 V
GND_DIG	57, 75	Ground of digital ADC circuits
GND_AN	60, 72	Ground of analog ADC circuits



#### 1.3.2 Control of the VLOW\_ADC & VHIGH\_ADC reference voltages

VLOW\_ADC & VHIGH\_ADC are the reference voltages for a 0 and 1023 code. A 2K-resistor ladder internally connects them. The appropriate 2 V and 4 V DC voltages can be obtained as in *Table 7: pins of the ADC*, and decoupled to ground.



#### 1.3.3 Non-linear and linear conversion mode – "gamma" correction

Figure 14: linear and non-linear ADC conversion characteristic

Figure 14 shows the ADC transfer characteristic. For this measurement, the ADC input was connected to a 16-bit DAC. The input voltage was a 100 KHz triangle waveform.

The non-linear ADC conversion is intended for gamma-correction of the images. It increases contrast in dark areas and reduces contrast in bright areas. The non-linear curve is tolerant for external pixel offset error correction. This means that pixel offset variations can be corrected by changing the offset after the non-linear AD conversion. This is so because the non-linear transfer function is

$$H(s) = 1 - exp(-a*s)$$

by design, and neglecting the offset, the relation between the non-linear output (y) and the linear output (x) is *exactly*:

$$Y = 1024 * (1 - exp(-x/713)) / (1 - exp(-1024/713))$$

This law yields an increased accuracy of about a factor 2 near the zero end of the scale. It is thus possible to obtain an effective 11 bit accuracy on a linear scale after post processing by applying the reverse law to the non-linear output:

$$Z = -2 * 713 * \ln(1 - y/(1024/(1 - \exp(-1024/713)))) = -1426 * \ln(1 - y/1343.5)$$

Then Z is an 11-bit linear output in the range 0...2047.





## **2** Operation of the image sensor

## 2.1 Set configuration & pulse timing

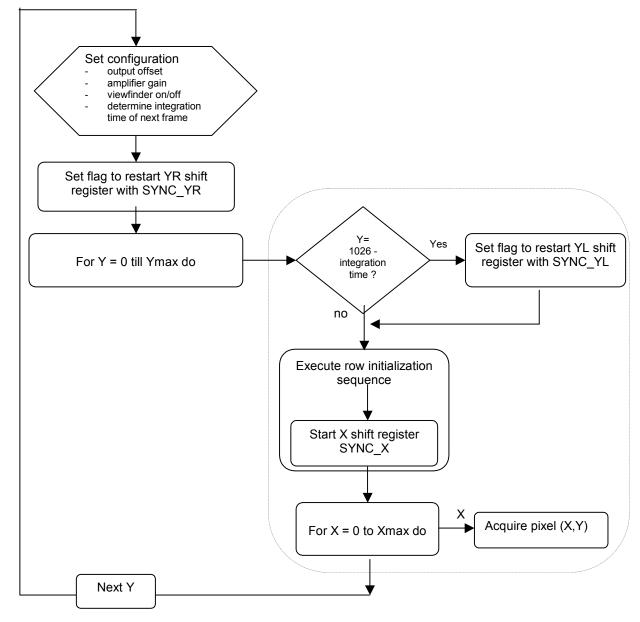


Figure 15: typical operation mode (readout of a frame)

Figure 15 shows a typical operation mode of the image sensor. At the start of a new frame, the device may be (re-)configured. If necessary, the output amplifier gain and offset are adjusted or the device is put in viewfinder mode.



Then, the *frame readout shift register* is initiated by pulsing "SYNC\_YR". This pulse occurs once per frame, normally as a part of the first row blanking sequence.

The readout of a row (line) starts with row blanking initialization sequence. Here several pulses are applied for Y-direction shift, the column amplifier S&H and nulling, and the start (SYNC\_X) of the X-direction shift register.

The *frame reset shift register* is started also once per frame by "SYNC\_YL", this pulse occurs once per frame, normally as a part of the row blanking sequence of one particular row. The time delay from the SYNC\_YL to SYNC\_YR is the integration time. The integration is thus a multiple of the row readout time. The reset shift register always leads the readout shift register. Therefore, the integration time should be determined before the start of the frame readout. The value that is fixed at that moment will be the integration time of the NEXT frame. If the value set for the integration time changes during frame readout, the start pulse might be lost and the next frame might be invalid. We will now discuss all steps in more detail.

#### 2.1.1 Set configuration

Configuration of the image sensor implies control & adjustment of the following points:

- output amplifier offset level, set by 'dac\_bit[0...3]'
- output amplifier gain setting, set by 'gc\_bit[0...3]'
- choose the integration time of the next frame
- set/clear viewfinder mode (pin 'subsampl')
- in case when the fast adjustment of the offset level is used, puls 'calib\_f' and 'unitygain' as described before in figures Figure 7 and Figure 8.

#### 2.1.2 Viewfinder mode vs. normal readout

 Table 8 : co-ordinate of the row or column selected by the Y/X shift registers after a # clock periods in viewfinder mode and full image mode

Clock	Sync	1	2	3	4	5	6	
Viewfinder mode	None	None	Row 1	Row 5	Row 9	Row 13	Row 17	Y reg.
			Dark	Col. 1	Col. 5	Col. 9	Col. 13	X reg.
Full image mode	None	None	Row 1	Row 2	Row 3	Row 4	Row 5	Y reg.
_			Dark	Col. 1	Col. 2	Col. 3	Col. 4	X reg.

Clock	258	259	260
Viewfinder mode	Row	Row	EOS
	1025	1029	

Clock Full image mode	1030 Row	1031 Row	1032 EOS
0	1029	1030	
	Y shift register		

322	323	324
Col.	Col.	EOS
1281	1285	Dark

1287	1288	1289	
Col.	Col.	EOS	
1285	1286	Dark	
X shift register			

In full image readout mode (pin 84, subsmpl = 0), the imager is a 1280 x 1024 SXGA image sensor. There are 3 dummy pixels read at all 4 borders of the image.

In viewfinder mode (subsmpl = 1), the imager acts as a 320 x 256 QVGA image sensor with one dummy pixel at the start of a row/column.

Table 8 shows which column or row is selected after a number of clock pulses.



#### 2.1.3 Start of the Y shift registers for row readout & row reset

The shift registers are put in their initial state by a synchronization- or start pulse. (sync\_x, sync\_yr, sync\_yl). The synchronization signal is low-active and should only be generated when the clock of the shift register is high. After the synchronization pulse, two falling clock edges are needed to skip dummy pixels/lines. On every falling clock edge, the shift register selects a new row for readout or reset. Figure 16 shows this timing.

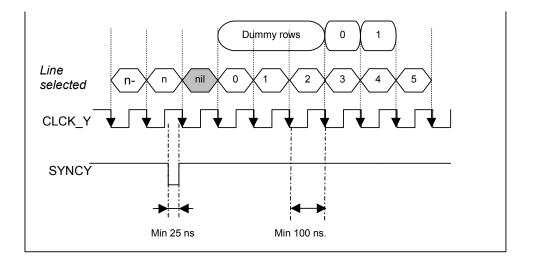


Figure 16: timing of Y shift registers (for row selection)

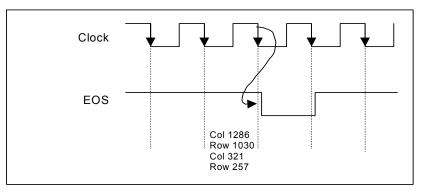


Figure 17 : End-of-scan pulse

#### 2.1.4 End-of-scan: EOS\_YL, EOS\_YR, EOS\_X

All 3 shift registers are equipped with 'end-of-scan' pulses. These pulses are low during the clock period after the last pixel or row has been read out, also in viewfinder mode.

At the EOS\_X pulse, the *electrical dark refe*rence level is put on the readout bus. This voltage remains on the bus until the SIN pulse goes high. During the row blanking time, this voltage can be used for the offset adjustment of the output amplifier. The *SIN high* forces the DCREF voltage on the output bus.



We advise *not to use* the EOS pulses as an input for the row blanking time sequence generation, but to use simple counters instead. If by some reasons the EOS signal is absent or subject to glitches, the system would hang. EOS is intended as diagnostic means.

#### 2.1.5 Row initialization

During the *row blanking time* (which occurs at the beginning of every row read), several tasks are executed: selection of a new row, readout of this row by double sampling, reset of a new row, and possibly (slow) offset adjustment of the output amplifier. Therefore, a pulse patterns must be applied to several signals during this time. There is some freedom to make this pattern. The constraints are listed below:

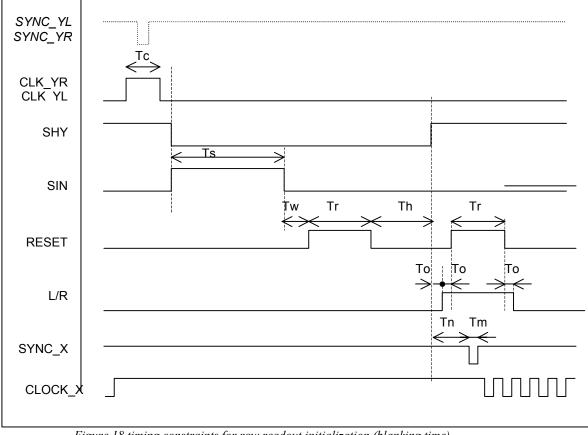


Figure 18 timing constraints for row readout initialization (blanking time)

Та	Min 0	Delay between falling edge of CLK_Y* and SHY or
		SIN
Tc	Min 25 ns	CLK_YR & CLK_YL high time
Ts	Typ. 3 us	On-time of SIN (offset calibration pulse)
		Delay between selection of new row and end of column
		amplifier calibration
Tw	Typ. 200 ns	Delay between end SIN and pixel reset
Tr	Typ. 1 us	On-time of reset pulse
Th	Typ 1 us	Th + Tr = Delay between pixel reset and column
		sample & hold

Table 9: timing constraints on row initialization pulses sequence



То	Typ 100 ns	Delay between SHY and L/R
		Overlap of $L/R$ over $2^{nd}$ reset pulse
Tm	Min 25 ns	On-time of one of the SYNC pulses. SYNC==low may
		only occur when the associated CLOCK is high.
Tn	Min. 200 ns	Delay between SHY and start row readout

Figure 18 and Table 9 illustrate the timing constraints of the row initialization/ blanking sequence.

- The EOS\_X pulse flags the end of the scanning of previous line, and should be considered as a diagnostic means only. The blanking sequence could start earlier or later.
- The next row (=line) is selected after the falling edge of CLK\_YR and CLK\_YL,
- The column amplifiers receive the signals on the pixels array columns buses when SHY is low (transparent).
- The SIN pulse (high) forces the column amplifiers in an "offset nulling" state.
- After 3 us, the column amplifiers have reached offset-free equilibrium, and the SIN pulse is brought low again. The pixel's signal level is thus stored in the column amplifier.
- After that the pixels in the selected row (line) are be reset (first pulse on RESET).
- Consequently the reset level is frozen in the column amplifiers when SHY goes high. Both signal level and reset level have now been applied to the column amplifiers. The sample hold (*SHY*) guarantees that this information will not change anymore during readout of the line.
- Now, the row is ready for readout. A pulse on SYNC\_X must be given to start the row readout. SYNC\_X initiates the X-direction scanning register. The scanning itself is controlled by CLOCK X.
- During the beginning of the row readout, or possibly before, the RESET pulse for the electronic shutter (ES) must be given, if the ES is used. This is a pulse on RESET together with a high level on L/R. If the ES is not used, L/R remains low and the second RESET pulse is not generated.

During some or the entire row blanking times, the output amplifier can be calibrated. If the slow calibration method is used, pulse the 'CALIB\_S' pin once per line. The calibration happens on the rising edge of the pulse.

If the fast calibration is used, the 'CALIB\_F' should be pulsed during the row blanking time of the first row only. This calibration happens during the time that the pulse is high.

During this calibration, the input applied to the amplifier must be the *dark reference*, which can either be the built-in *electrical dark reference*, or an external dark reference on the pin EXTIN.

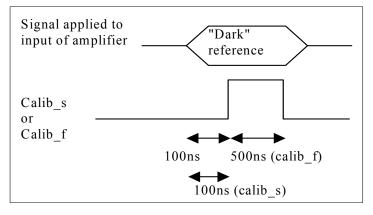


Figure 19: pulse on 'CALIB\_F'& 'UNITYGAIN' to be given once per frame, or on CALIB\_S once per line



#### 2.1.6 The X-direction shift register

The X shift register behaves like the Y shift registers.

The sequence if initiated by SYNC\_X, which should occur when CLOCK\_X is high. As CLOCK\_X is halted during the blanking time, the SYNC\_X pulse could occur anywhere, and be taken equal to some other pulse (e.g. CLOCK Y).

The first real (dummy) pixel is read out after the 3<sup>rd</sup> falling edge on the clock. Dummy pixels are perfectly operational pixels, but are added to shield the "real" pixels from the cross talk of the periphery.

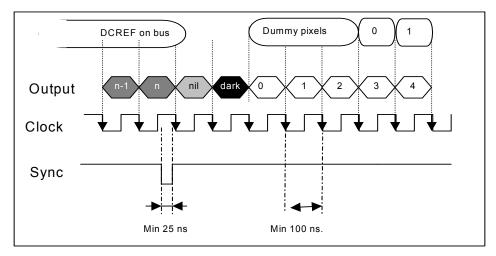


Figure 20 : timing of X shift register and pixels read-out

#### **On-chip generated electrical dark references**.

The sensor outputs a electrical dark reference level after the 2<sup>nd</sup> falling edge on the clock (after sync). At the end of the row readout, after EOS\_X becomes low, the sensor outputs the electrical dark reference voltage also, and it remains present on the on the readout bus until the SIN goes high. Note that if the X-register is reset before the EOS is reached, the dark reference is not put on the bus. Use the dark reference of the beginning of the line instead.



#### 2.1.7 Pixel readout

The same continuous 10 MHz clock drives CLK\_ADC and CLK\_X. On the falling edge of CLK\_X, a new pixel is selected and propagates to the output amplifier. At the same time, the ADC input is frozen by the falling edge on CLK\_ADC. The digital output has a delay of one pixel compared to the analog signal. The digital output becomes valid between 25 to 50 ns after the falling edge on CLK\_ADC.

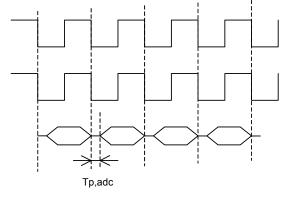
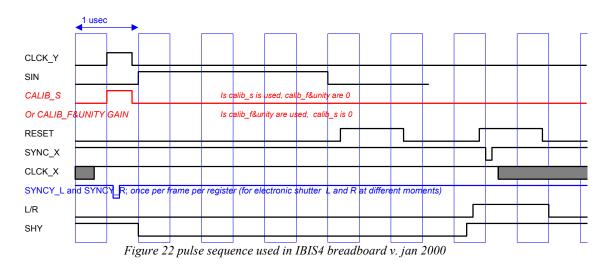


Figure 21: pixel timing

If the end of a row is reached, the sensor outputs an end-of-scan (EOS) pulse during one pulse period. And the electrical black reference level appears at the output for all successive pulses. So, the same 10 MHz clock can drive CLK\_X and CLK\_ADC.

#### 2.1.8 Example: timing used on the IBIS4 breadboard

The next figure is the timing as used in the IBIS4 breadboard version 12 jan 2000. In this baseline only CALIB\_F is used (pulsing once per frame). CALIB\_S (pulse every line) is shown as reference, but is actually not used in the baseline. The UNITY\_GAIN pulse is identical to CALIB\_F.





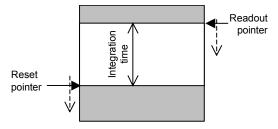
### **2.2 Illumination control**

There are two means of controlling the illumination level electrically. For high light levels, there is an electronic shutter. For low light levels, the output signal can be amplified by controlling the output amplifier gain. The offset level of the signal can also be controlled digitally.

#### 2.2.1 "Rolling curtain" electronic shutter

The electronic shutter can reduce the integration time (= exposure time). This is achieved by an additional reset pulse every frame. In this way, the integration time is reduced to a fraction of the frame readout time.

There are two Y shift registers. One of them points at the row that is currently being read out. The other shift register points at the row that is currently being reset. Both pointers are shifted by the same Y-clock and move over the focal plane. The integration time is set by the delay between both pointers.



*Figure 23 schematic representation of the curtain type electronic shutter* 

This is a so-called 'rolling curtain'-type shutter. It 'rolls' over the focal plane.

The left and right shift registers can be used both for pointing to the row that is readout or the row that is reset. The shift register that is active for readout or reset is selected by the signal on L/R. In the above timing diagrams, we use the R shift register for readout, and the L shift register for electronic shutter reset. We call them the readout shift register and reset shift register.

The integration time is controlled by the delay between the SYNCY\_L and SYNCY\_R pulse. The shorter this delay, the shorter the integration time and the smaller the output signal will be.

If the electronic shutter is not used, the L/R signal is not pulsed. The integration time is then equal to the frame readout time.

For proper operation of the ES, the CLOCK\_Y must come as an uninterrupted pulse train. Also during the dead time between frames the CLOCK\_Y must be clocked. The reason is that each line should see the same elapsed time between the "ES-reset" and the reset of the line being read-out. If the CLOCK\_Y is halted, the lines between the two pointers will have a longer effective integration time, and appear brighter.

#### 2.2.2 Gain control

For low illumination levels, the electronic shutter is not used - or set to its maximal value. Longer integration times can only be obtained by decreasing the frame rate. As an alternative or in complement, one can increase the output amplifier gain.

The gain is controlled by a 4-bit word. Gain values vary between 1.2 and 16, and on an exponential scale, as the F-stops of a lens.



Of course, increasing the signal amplitude by increasing the gain, will also increase the noise level. The apparent increase of sensitivity is at the cost of a lower dynamic range.

#### 2.2.3 Offset level adjustment

The offset level of the output signal is set by a 4-bit digital word. The offset level voltage is selected between VLOW\_DAC and VHIGH\_DAC on 16 taps.

### 2.3 "Double slope" or "High-dynamic range" mode

IBIS4-1300 has a feature to increase the dynamic range. The pixel response can be extended over a larger range of light intensities by using a "dual slope integration" (patents pending). This is obtained by the addition of charge packets from a long and a short integration time in the pixel during the same frame time.

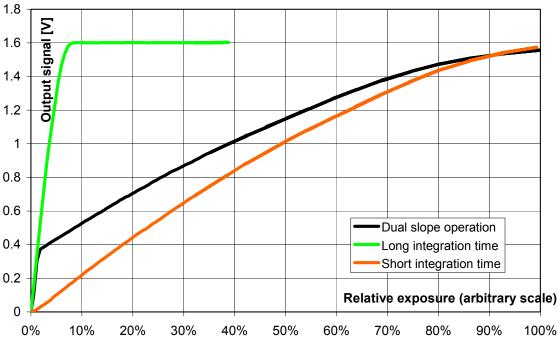


Figure 24: response curve of the pixels in dual slope integration

Fig.24 shows the response curve of a pixel in dual slope integration mode. The curve also shows the response of the same pixel in linear integration mode, with a long and short integration time, at the same light levels.

Dual slope integration is obtained by

- Feeding a lower supply voltage to VDD\_RESETL. E.g. apply 4 to 4.5 Volts. The difference between this voltage and VDD determines the range of the high sensitivity, thus the output signal level at which the transition between high and low sensitivity occurs.
- Put the amplifier gain to the lowest value where the analog output swing covers the ADC's digital input swing. Increasing the amplification too much will likely boost the high sensitivity part over the whole ADC range.
- The electronic shutter determines the ratio of integration times of the two slopes. The high sensitivity ramp corresponds to "no electronic shutter", thus maximal integration time. The low



sensitivity ramp corresponds to the electronics shutter value that would have been obtained in normal operation.

These example images are found at http://www.fillfactory.com/htm/technology/htm/dual-slope.htm



Figure 25 Linear long exposure time



Figure 26 Linear short exposure time



Figure 27 Double slope integration

IBIS4-1300 Datasheet



### 2.4 Electrical parameters

#### 2.4.1 DC voltages

#### VDD and GND:

Nominal VDD-GND is 5V DC. Overall current consumption for the different parts

- imager core + output amplifier analog
- imager core digital
- ADC analog
- ADC digital

Are quoted in the datasheets The sensor works properly when using a 7805 type of regulator. Decoupling VDD to GND must happen close to the IC.

#### Other applied DC voltages

Should be clean as the VDD. Can be derived by resistive division of VDD-GND, and decoupled to VDD or GND (as indicated)

#### **External Resistors**

Are used as current mirror settings. Should be decoupled to the opposite rail voltage as the connection of the resistor (thus: if the resistor is tied to VDD, the capacitor is tied to GND). In practice the decoupling can be omitted for almost all signals - to be experimented.

#### 2.4.2 Input / output

#### **Digital inputs:**

Clean rail to rail CMOS levels. 10%-90% rise and fall times between 10 ns and 40 ns

#### **Digital outputs:**

Deliver CMOS level, able to drive 40 pF capacitive loads

#### Analog output of imager core

Designed to drive a 40 pF capacitive load

#### Analog input of ADC

Is equivalent to a capacitive load of typ. 15 pF.



## **Pin configuration**

### 2.5 Pin list

#### Signal type symbols

Α	Analog
D	Digital
W	Word bit

#### I/O Symbols

I Input

O Output

P Power supply

G Ground

No.	Name	Typ e	I/O	Description	Signal	
4	<b>N</b> 11 - 1					
1	Nbiasarray	A		1MEG to VDD and decouple to GND	Pixel source follower bias current	
2	pbias2	A	I	1MEG to GND and decouple to VDD	Column amp 1st source follower (after SHY) bias current	
3	Pbias	A	I	1MEG to GND and decouple to VDD	current	
4	xmux_nbias	A	I	100K to VDD and decouple to GND	X-multiplexing bias current (/6)	
5	Sync_yr\	D		low active (0=sync)	0 = reset right shift register	
6	clk_yr	D	Ι	Shifts on falling edge	clock right shift register	
7	Eos_yr\	D	0	Active low	low 1st clk_yr pulse after last row	
8	Eos_x\	D	0	Active low	low 1st clk_x pulse after last active column	
9	Selextin	D	I	input selector for output amplifier	1 = external input; [0] = imager core	
10	Gnd	А	G	Analog GND		
11	Vdd	А	Ρ	Analog VDD	+ 5 V DC	
12	Extin	A	I	external input to output amplifier		
13	Output	А	0	analog output of imager core	Connect to in_adc (p73)	
14	Vlow_dac	А	Ι	low reference voltage offset DAC	+/- 1 V	
15	Vhigh_dac	A	I	high reference voltage offset DAC	+/- 2.5 V	
16	Calib_s	D	I	Slow dark offset level adjustment	0: connect to cap (st2) and in- (st1) 1: connect to rdac (st2) and output (st1)	
17	gc_bit0	W	Ι	Lsb	gain control output amplifier	
18	gc_bit1	W	I			
19	gc_bit2	W	I		]	
20	gc_bit3	W	I	Msb		

#### IBIS4-1300 Datasheet



22 Ci 23 Di 24 Di 25 Di 26 Di 27 Ni 28 Si 29 Cl 30 sh 31 do 32 do 33 gr 34 vc 35 si 36 sy 37 Cl 38 ec 39 bi 40 se	Jnitygain Calib_f Dac_b3 Dac_b2 Dac_b1 Dac_b0 Nbias_oamp Sync_x\ Sync_x\ Sync_x\ Sync_y\ Iccon Icref gnd vdd sin Sync_y\I Sync_y\I Sync_y\I	D W W A D D D A A A A A D	 	sets output amplifier in unity gain fast dark offset level calibration Msb Lsb 100K to VDD and decouple to GND low active (0=sync) Shifts on falling edge Column parallel track and hold control voltage for DC reference generation reference voltage	High active High active dac control for black offset level dac control for black offset level dac control for black offset level dac control for black offset level output amplifier bias current 0 = reset X shift register clock X shift register 1 = hold; 0 = track Connect to GND (default) Should be +/- 1.2 V, depends on dccon
23         Di           24         Di           25         Di           26         Di           27         Ni           28         Sy           29         cl           30         sf           31         dc           32         dc           33         gr           34         vc           35         si           36         sy           37         cl           38         ec           39         bi           40         se	Dac_b3           Dac_b1           Dac_b0           Dac_b0           Dac_b0           Sync_x\           Sync_x\           Sk_x           Shy           Iccon           Icref           ynd           /dd           sin           sync_y\l	W W A D D D A A A A	I I I I I O G P	Msb Lsb 100K to VDD and decouple to GND low active (0=sync) Shifts on falling edge Column parallel track and hold control voltage for DC reference generation	dac control for black offset level dac control for black offset level dac control for black offset level dac control for black offset level output amplifier blas current 0 = reset X shift register clock X shift register 1 = hold; 0 = track Connect to GND (default) Should be +/- 1.2 V, depends on
24         Di           25         Di           26         Di           27         Ni           28         Si           29         cll           30         sf           31         dc           32         dc           33         gr           34         vc           35         sii           36         sy           37         cll           38         ec           39         bi           40         se	Dac_b2 Dac_b1 Dac_b0 Nbias_oamp Sync_x\ Sk_x shy dccon dcref gnd vdd sin sync_y\l ck_yl	W W A D D A A A A	I I I I I O G P	Lsb 100K to VDD and decouple to GND low active (0=sync) Shifts on falling edge Column parallel track and hold control voltage for DC reference generation	dac control for black offset level dac control for black offset level dac control for black offset level output amplifier bias current 0 = reset X shift register clock X shift register 1 = hold; 0 = track Connect to GND (default) Should be +/- 1.2 V, depends on
25         Di           26         Di           27         NI           28         Sy           29         cli           30         sr           31         dc           32         dc           33         gr           34         vc           35         sii           36         sy           37         cli           38         ec           39         bi           40         se	Dac_b1 Dac_b0 Nbias_oamp Sync_x\ Sync_x\ Ik_x shy dccon dcref dcref gnd rdd sin sync_y\l Sk_yl	W A D D A A A A A	 	100K to VDD and decouple to GND low active (0=sync) Shifts on falling edge Column parallel track and hold control voltage for DC reference generation	dac control for black offset level dac control for black offset level output amplifier bias current 0 = reset X shift register clock X shift register 1 = hold; 0 = track Connect to GND (default) Should be +/- 1.2 V, depends on
26         Di           27         NI           28         Si           29         cli           30         str           31         dc           32         dc           33         gr           34         vc           35         sii           36         sy           37         cli           38         ec           39         bi           40         se	Dac_b0 Nbias_oamp Sync_x\ Slk_x shy dccon dcref dcref gnd rdd sin sync_y\l clk_yl	W A D D A A A A A	 	100K to VDD and decouple to GND low active (0=sync) Shifts on falling edge Column parallel track and hold control voltage for DC reference generation	dac control for black offset level output amplifier bias current 0 = reset X shift register clock X shift register 1 = hold; 0 = track Connect to GND (default) Should be +/- 1.2 V, depends on
27 Ni 28 Sy 29 Cl 30 st 31 dc 32 dc 33 gr 34 vc 35 si 36 sy 37 Cl 38 ec 39 bi 40 se	Nbias_oamp Sync_x\ Shy Shy dccon dcref gnd /dd sin sync_y\l Sk_yl	A D D A A A A	I I I O G P	100K to VDD and decouple to GND low active (0=sync) Shifts on falling edge Column parallel track and hold control voltage for DC reference generation	output amplifier bias current 0 = reset X shift register clock X shift register 1 = hold; 0 = track Connect to GND (default) Should be +/- 1.2 V, depends on
28 Sy 29 cl 30 sh 31 dd 32 dd 32 dd 33 gr 34 vc 35 si 35 si 36 sy 37 cl 38 ec 39 bi 40 se	Sync_x\ Sk_x shy dccon dcref gnd /dd sin sync_y\l Sk_yl	D D A A A A A	 	GND low active (0=sync) Shifts on falling edge Column parallel track and hold control voltage for DC reference generation	0 = reset X shift register clock X shift register 1 = hold; 0 = track Connect to GND (default) Should be +/- 1.2 V, depends on
29         cli           30         sh           31         dc           32         dc           33         gr           34         vc           35         sii           36         sy           37         cli           38         ec           39         bi           40         se	lk_x shy dccon dcref ynd ydd sin sync_y\l	D A A A A A	I I O G P	Shifts on falling edge Column parallel track and hold control voltage for DC reference generation	clock X shift register 1 = hold; 0 = track Connect to GND (default) Should be +/- 1.2 V, depends on
30         sh           31         dc           32         dc           33         gr           34         vc           35         sii           36         sy           37         cll           38         ec           39         bi           40         se	shy lccon lcref gnd /dd sin sync_y\l	D A A A A	I O G P	Column parallel track and hold control voltage for DC reference generation	1 = hold; 0 = track Connect to GND (default) Should be +/- 1.2 V, depends on
31         dc           32         dc           33         gr           34         vc           35         sii           36         sy           37         cli           38         ec           39         bi           40         se	Iccon Icref gnd vdd sin sync_y\l	A A A A	I O G P	Column parallel track and hold control voltage for DC reference generation	Connect to GND (default) Should be +/- 1.2 V, depends on
32 dc 33 gr 34 vc 35 sii 36 sy 37 cl 38 ec 39 bi 40 se	dcref gnd vdd sin sync_y\l	A A A	O G P	reference generation	Should be +/- 1.2 V, depends on
33         gr           34         vc           35         sii           36         sy           37         cli           38         ec           39         bi           40         se	gnd /dd sin sync_y\l	A A	G		
33         gr           34         vc           35         sii           36         sy           37         cli           38         ec           39         bi           40         se	gnd /dd sin sync_y\l	A A	G		
34         vc           35         sii           36         sy           37         cll           38         ec           39         bi           40         se	/dd sin sync_y\l slk_yl	А	Ρ		
34         vc           35         sii           36         sy           37         cll           38         ec           39         bi           40         se	/dd sin sync_y\l slk_yl	А	Ρ		
34         vc           35         sii           36         sy           37         cll           38         ec           39         bi           40         se	/dd sin sync_y\l slk_yl	А	Ρ		
35         sin           36         sy           37         cll           38         ec           39         bit           40         se	sin sync_y\l slk_yl				+ 5 V DC
36         sy           37         cli           38         ec           39         bi           40         se	sync_y\l clk_yl	5		Column amplifier calibration	1 = calibrate, see timing diagram
37         cli           38         ec           39         bir           40         se	:lk_yl		•	signal	
37         cli           38         ec           39         bir           40         se	:lk_yl	D	Ι	0 = start left shift register	low active (0=sync)
38 ec 39 bi 40 se		D	I	clock left shift register	Shifts on falling edge
39 bi 40 se	, , , , , , , , , , , , , , , , , , ,	D	0	low 1st clk yl pulse after last	Active low
40 se		2	Ŭ	row	
40 se	oitinvert	D	Ι	High active, 1 = invert bits	inverts ADC output bits
	select	D	Ι	High active	selects row indicated by left/right
		_	•		shift register
41 re	eset	D	Ι	High active	resets row indicated by left/right
				5	shift register
42 d9	19	W	0	MSB	ADC output
43 d8	18	W	0		
44 d7	17	W	0		
45 d6	16	W	0		
46 d5	15	W	0		
47 d4	4	W	0		
48 d3	13	W	0		
49 d2	12	W	0		
50 d1	1	W	0		
51 d0		W	0	LSB	
	gnd	А	G		
•	/dd	Α	P	+ 5 V DC	
			•		
54 gr	gnd_ab	Α	G	Anti-blooming drain voltage	GND or +1V for improved anti- blooming
55 vo	/dd_array	А	Р	+ 5 V DC	Pixel power supply
	/dd_dig	D	Р	+ 5 V DC	ADC digital power supply
-	gnd_dig	D	G		ADC ground of digital circuits
-	/dd an	A	P	+ 5 V DC	ADC analog power supply
-	/dd_resetl	A	P	5 V DC default	VDD for reset by left shift register
			•	(5.5 V for large output swing)	
				44.5 V for double slope mode	
60 gr		А	G		ADC ground of analog circuits

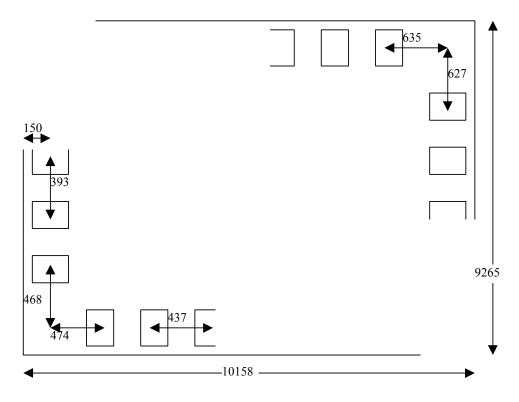


	1					
61	vhigh_adc	Α	Ι	+ 4 V DC	High ADC reference voltage	
62	clk_adc	D	Ι	ADC Clock	Converts on falling edge	
63	tri_adc	D	Ι	ADC output tristate control	1=tristate; 0=output	
64	pbiasdig1	Α	Ι	100K to GND and decouple to	current bias for comparator after	
				VDD	encoder	
65	pbiasencload	А	Ι	100K to GND and decouple to	current bias for encoder	
				VDD		
66	pbiasdig2	А	Ι	100K to GND and decouple to	current bias for digital logic in	
		-		VDD	columns	
67	nonlinear	D	I	high active (1 = non-linear	control for non-linear behavior of	
				conversion)	sensor	
	n.c.			not connected		
69	nbiasana2	А	I	100K to VDD and decouple to	bias current 2nd comparator stage	
70		٨	1	GND	biog gumant dat generater stars	
70	nbiasana	А	I	100K to VDD and decouple to GND	bias current 1st comparator stage	
71	vlow adc	А		+ 2 V DC, +-2 K between P71	Low ADC reference voltage	
/ 1	viow_auc	A	1	and P61	Low ADC reference voltage	
72	gnd_an	А	G		ADC ground of analog circuits	
	in adc	A	<u> </u>	Converts between vlow and	ADC input	
10	m_ddc	~	•	vhigh (2-4V)		
74	vdd an	А	Р	+ 5 V DC	ADC analog power supply	
-						
75	gnd_dig	D	G		ADC ground of digital circuits	
76	vdd dig	D	Р	+ 5 V DC	ADC digital power supply	
77	vdd	А	Р	+ 5 V DC		
78	gnd	А	G			
79	vdd resetr	А	Р	5 V DC default	Power supply for reset by right	
			-	(5.5 for large signal swing)	(readout) shift register	
80	L/R\	D	Ι	1=left; 0=right	Selects left or right shift register for	
				, C	'select' and 'reset'	
81	Pixel diode	Α	0	groups current of 24 x 18 pixels	Test structure for spectral response	
					measurement of pixels	
82	Photodiode	А	0	168x126 um2 (eq. 24 x 18	Test structure for spectral response	
				pixels)	measurement of photodiode	
83	clip	А	Ι	Clips if output > 'clip' - Vth	Clipping voltage for output amplifier	
		_		(PMOS)		
84	subsmpl	D	I	high active, 1 = subsampling	Selects viewfinder mode $(1:4 = 320)$	
					x 256)	



### 2.6 Bonding pad geometry for the IBIS4-1300

- The 84 pins are distributed evenly around the perimeter of the Chip. At each edge there are 21 • pins. Pin 1 is (in this drawing) in the middle of the left edge.
- The opening in the bonding pads (the useful area for bonding) is 200 x 150 um. •
- The centers of the bonding pads are at all four edges at 150 um distance from the nominal chip • border.
- The scribe line (=the spacing between the nominal borders of neighboring chips) is 250 um. •
- The bonding pad pitch is 437 um in X-direction •
- The bonding pad pitch in Y-direction is 393 um •
- Relative position of pads in corners: see next figure (measures in um). •



#### 2.6.1 Color filter geometry

Sensors with diagonal pattern have -pixel (1,1) is RED ..BGRBG**R** -first line sequence is ← -second line sequence is ..RBGRBG ←

sensors with Bayer pattern have vival (1 1) is GRE

-pixel $(1,1)$ is GREEN		
-first line sequence is	←	GRGR <b>G</b>
-second line sequence is	←	BGBGB

В



## 3 Package

84 pins ceramic LCC package (JLCC also available) Standard 0.04 inch pitch outline 0.46" square cavity

Die thickness nominally 711 um +- 50um Clearance from top of die to bottom of glass lid: 400um nominally

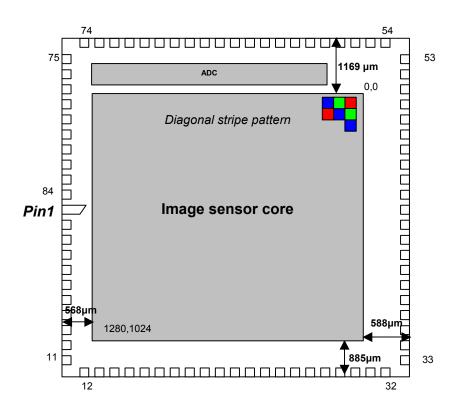


Fig22. Pin layout and package, top view



## 3.1 Cover glass

Size 18x18 mm for JLCC& LCC

#### 3.1.1 Color sensor

Refractive index:	1,55
Thickness:	0,75+-0.05 mm
Material:	BG39

This material acts a NIR cut-off filter. The transmission characteristics are given in the figure below. The data used to create the transmission curve of the BG39 material can be obtained as an excel file upon simple request to <u>info@fillfactory.com</u>.

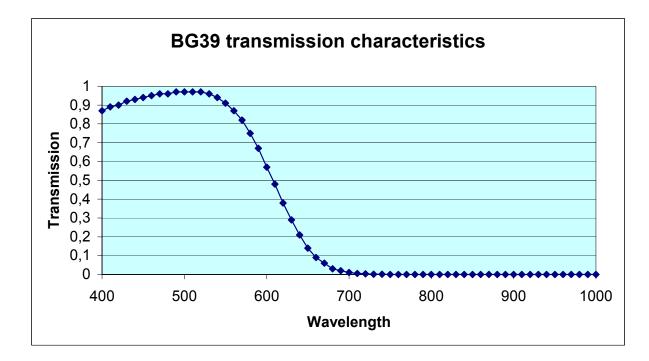


Figure 28: Transmission characteristics of the BG39 glass used as NIR cut-off filter for the FUGA1000 color image sensors



#### 3.1.2 Monochrome sensor

Refractive index:	1,52
Thickness:	0,55+-0.05 mm
Material:	D263

The transmission characteristics are given in the figure below.

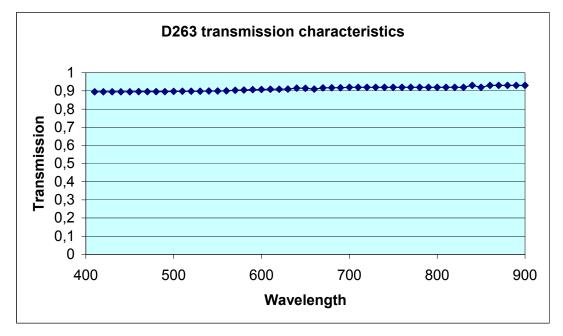


Figure 26: Transmission characteristics of the D263 glass used as protective cover for the IBIS4-1300 monochrome image sensors



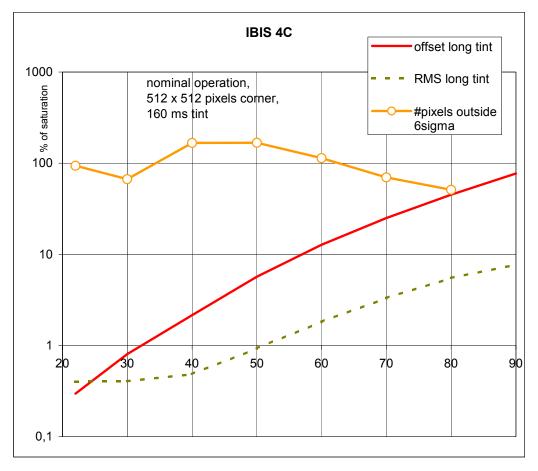
## **4** Ordering Information

Table 10: FillFactory and Cypress part numbers

FillFactory Part Number	Cypress Semiconductor Part Number
IBIS4-1300-C1-2	CYII4SD1300AA-QAC – Preliminary
IBIS4-1300-M-1	CYII4SM1300AA-HBC – Preliminary
IBIS4-1300-M-2	CYII4SM1300AA-QBC – Preliminary

## 5 FAQ

#### 5.1.1 Temperature dependence of dark signal





The above graph is measured on an IBIS4-1300 under nominal operation, using breadboard. This particular sensor has about 100 "bad pixels" at RT.

Average offset (=dark signal) and RMS (=FPN of dark signal) are measured versus temperature. Offset is referred to the "short tint" offset at 20 C. Integration time was 160 ms (= "long tint"). Y-axis is the output signal (100% = ADC range)

#### 5.1.2 Useful range of "double slope"

Which total dynamic range can reasonably be obtained with the dual slope feature of the IBIS4-1300? Assuming that the "regular" S/N is 2000:1, and that one can put the knee point halfway the voltage range, the each piecewise linear halve has 1000:1 S/N. If the ratio between slopes is a, then the total dynamic range becomes (1000+a\*1000):1.

Example, is a=10, then the total dynamic range becomes 11000:1.

In practice, acceptable images are obtained with a up to 10. Larger a's are useable, but near the knee, contrast artifacts become annoying.

#### 5.1.3 Skipping rows or columns

Although these modes are not described in the datasheets, it is possible to skip rows or columns by simply applying additional CLK\_YR + CLR\_YL, or CLK\_X pulses. The maximum clock frequency is not documented. But it is probable that one can reach at least 10 MHz in Y and 40 MHz in X.

## Disclaimer

FillFactory image sensors are only warranted to meet the specifications as described in the production data sheet. Specifications are subject to change without notice.

## **Document history record**

Issue	Date	Description of changes	
7.1	January, 2005	Cypress logo and part numbers added. Application notes references deleted. Added Cypress Document # 38-05707 Rev ** in	
		the document footer.	



### **Document History Page**

Document Title:IBIS4-1300 1.3 M Pixel Rolling Shutter CMOS Image SensorDocument Number:38-05707

Rev.	ECN No.	Issue Date	Orig. of Change	Description of Change
**	310213	See ECN	SIL	Initial
				Cypress
				release

(EOD)